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What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Active
Core Processor	ARM® Cortex®-M0+
Core Size	32-Bit Single-Core
Speed	20MHz
Connectivity	I²C, SPI, UART/USART
Peripherals	LVD, PWM, WDT
Number of I/O	57
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	256 x 8
RAM Size	4K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 16x12b; D/A 2x6b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	64-QFP
Supplier Device Package	64-QFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mke02z64vqh2

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1 Ordering parts

1.1 Determining valid orderable parts

Valid orderable part numbers are provided on the web. To determine the orderable part numbers for this device, go to [nxp.com](#) and perform a part number search for the following device numbers: KE02Z.

2 Part identification

2.1 Description

Part numbers for the chip have fields that identify the specific part. You can use the values of these fields to determine the specific part you have received.

2.2 Format

Part numbers for this device have the following format:

Q KE## A FFF R T PP CC N

2.3 Fields

This table lists the possible values for each field in the part number (not all combinations are valid):

Field	Description	Values
Q	Qualification status	<ul style="list-style-type: none"> M = Fully qualified, general market flow P = Prequalification
KE##	Kinetis family	<ul style="list-style-type: none"> KE02
A	Key attribute	<ul style="list-style-type: none"> Z = M0+ core
FFF	Program flash memory size	<ul style="list-style-type: none"> 16 = 16 KB 32 = 32 KB 64 = 64 KB
R	Silicon revision	<ul style="list-style-type: none"> (Blank) = Main A = Revision after main

Table continues on the next page...

4 Ratings

4.1 Thermal handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
T_{STG}	Storage temperature	-55	150	°C	1
T_{SDR}	Solder temperature, lead-free	—	260	°C	2

1. Determined according to JEDEC Standard JESD22-A103, *High Temperature Storage Life*.
2. Determined according to IPC/JEDEC Standard J-STD-020, *Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices*.

4.2 Moisture handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
MSL	Moisture sensitivity level	—	3	—	1

1. Determined according to IPC/JEDEC Standard J-STD-020, *Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices*.

4.3 ESD handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
V_{HBM}	Electrostatic discharge voltage, human body model	-6000	+6000	V	1
V_{CDM}	Electrostatic discharge voltage, charged-device model	-500	+500	V	2
I_{LAT}	Latch-up current at ambient temperature of 125°C	-100	+100	mA	3

1. Determined according to JEDEC Standard JESD22-A114, *Electrostatic Discharge (ESD) Sensitivity Testing Human Body Model (HBM)*.
2. Determined according to JEDEC Standard JESD22-C101, *Field-Induced Charged-Device Model Test Method for Electrostatic-Discharge-Withstand Thresholds of Microelectronic Components*.
3. Determined according to JEDEC Standard JESD78D, *IC Latch-up Test*.
 - Test was performed at 125 °C case temperature (Class II).
 - I/O pins pass ± 100 mA I-test with I_{DD} current limit at 800 mA.
 - I/O pins pass +60/-100 mA I-test with I_{DD} current limit at 1000 mA.
 - Supply groups pass 1.5 V_{ccmax}.
 - RESET pin was only tested with negative I-test due to product conditioning requirement.

Nonswitching electrical specifications

Table 3. DC characteristics (continued)

Symbol	C	Descriptions			Min	Typical ¹	Max	Unit
V_{OH}	P	Output high voltage	All I/O pins, except PTA2 and PTA3, standard-drive strength	5 V, $I_{load} = -5 \text{ mA}$	$V_{DD} - 0.8$	—	—	V
	C			3 V, $I_{load} = -2.5 \text{ mA}$	$V_{DD} - 0.8$	—	—	V
	P		High current drive pins, high-drive strength ²	5 V, $I_{load} = -20 \text{ mA}$	$V_{DD} - 0.8$	—	—	V
	C			3 V, $I_{load} = -10 \text{ mA}$	$V_{DD} - 0.8$	—	—	V
I_{OHT}	D	Output high current	Max total I_{OH} for all ports	5 V	—	—	-100	mA
				3 V	—	—	-60	
V_{OL}	P	Output low voltage	All I/O pins, standard-drive strength	5 V, $I_{load} = 5 \text{ mA}$	—	—	0.8	V
	C			3 V, $I_{load} = 2.5 \text{ mA}$	—	—	0.8	V
	P		High current drive pins, high-drive strength ²	5 V, $I_{load} = 20 \text{ mA}$	—	—	0.8	V
	C			3 V, $I_{load} = 10 \text{ mA}$	—	—	0.8	V
I_{OLT}	D	Output low current	Max total I_{OL} for all ports	5 V	—	—	100	mA
				3 V	—	—	60	
V_{IH}	P	Input high voltage	All digital inputs	$4.5 \leq V_{DD} < 5.5 \text{ V}$	$0.65 \times V_{DD}$	—	—	V
				$2.7 \leq V_{DD} < 4.5 \text{ V}$	$0.70 \times V_{DD}$	—	—	
V_{IL}	P	Input low voltage	All digital inputs	$4.5 \leq V_{DD} < 5.5 \text{ V}$	—	—	$0.35 \times V_{DD}$	V
				$2.7 \leq V_{DD} < 4.5 \text{ V}$	—	—	$0.30 \times V_{DD}$	
V_{hys}	C	Input hysteresis	All digital inputs	—	$0.06 \times V_{DD}$	—	—	mV
$ I_{In} $	P	Input leakage current	Per pin (pins in high impedance input mode)	$V_{IN} = V_{DD}$ or V_{SS}	—	0.1	1	μA
$ I_{INTOT} $	C	Total leakage combined for all port pins	Pins in high impedance input mode	$V_{IN} = V_{DD}$ or V_{SS}	—	—	2	μA
R_{PU}	P	Pullup resistors	All digital inputs, when enabled (all I/O pins other than PTA2 and PTA3)	—	30.0	—	50.0	$\text{k}\Omega$
R_{PU}^3	P	Pullup resistors	PTA2 and PTA3 pins	—	30.0	—	60.0	$\text{k}\Omega$
I_{IC}	D	DC injection current ^{4, 5, 6}	Single pin limit	$V_{IN} < V_{SS}, V_{IN} > V_{DD}$	-2	—	2	mA
			Total MCU limit, includes sum of all stressed pins		-5	—	25	
C_{in}	C	Input capacitance, all pins		—	—	—	7	pF
V_{RAM}	C	RAM retention voltage		—	2.0	—	—	V

1. Typical values are measured at 25 °C. Characterized, not tested.
2. Only PTB4, PTB5, PTD0, PTD1, PTE0, PTE1, PTH0, and PTH1 support high current output.

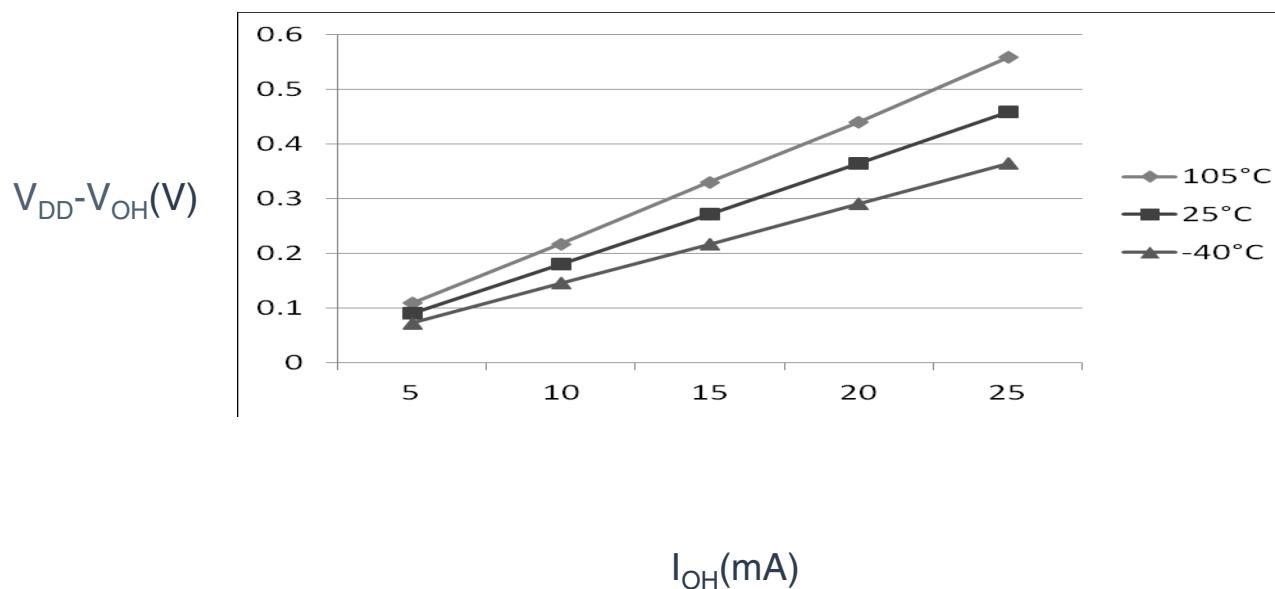


Figure 3. Typical $V_{DD} - V_{OH}$ Vs. I_{OH} (high drive strength) ($V_{DD} = 5$ V)

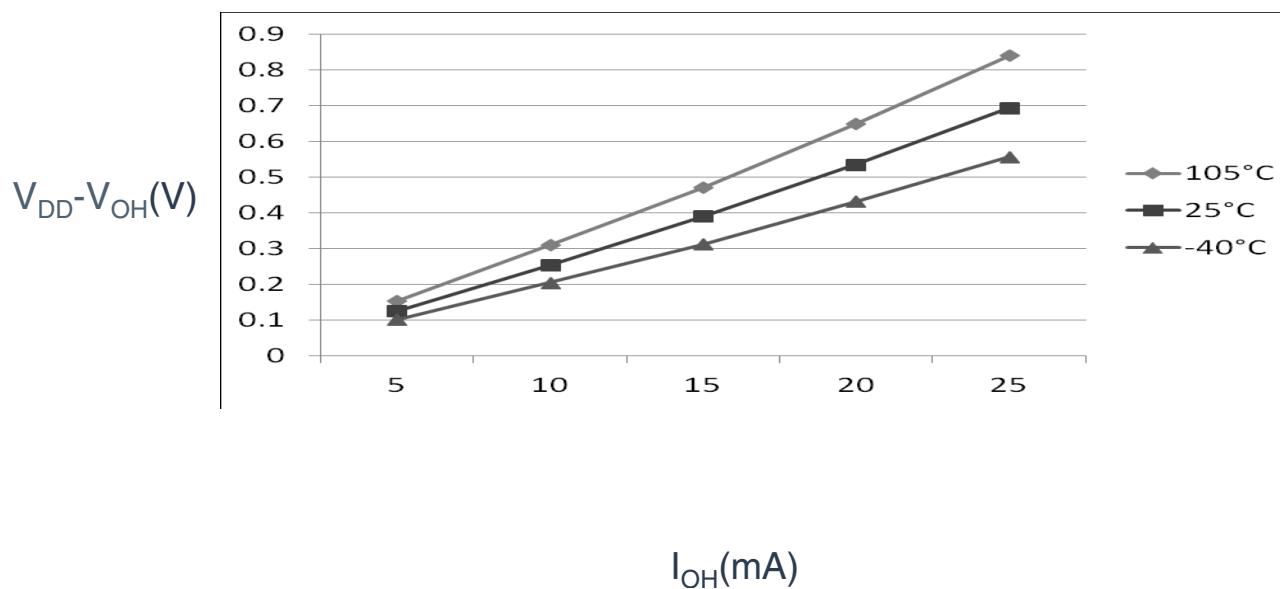


Figure 4. Typical $V_{DD} - V_{OH}$ Vs. I_{OH} (high drive strength) ($V_{DD} = 3$ V)

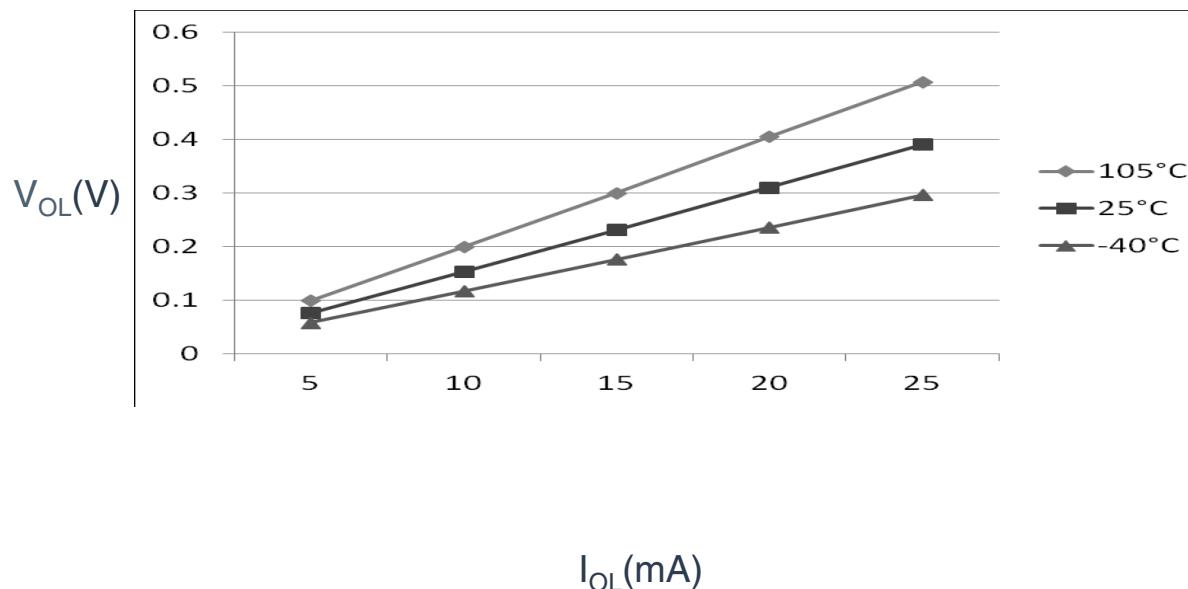


Figure 7. Typical V_{OL} Vs. I_{OL} (high drive strength) ($V_{DD} = 5$ V)

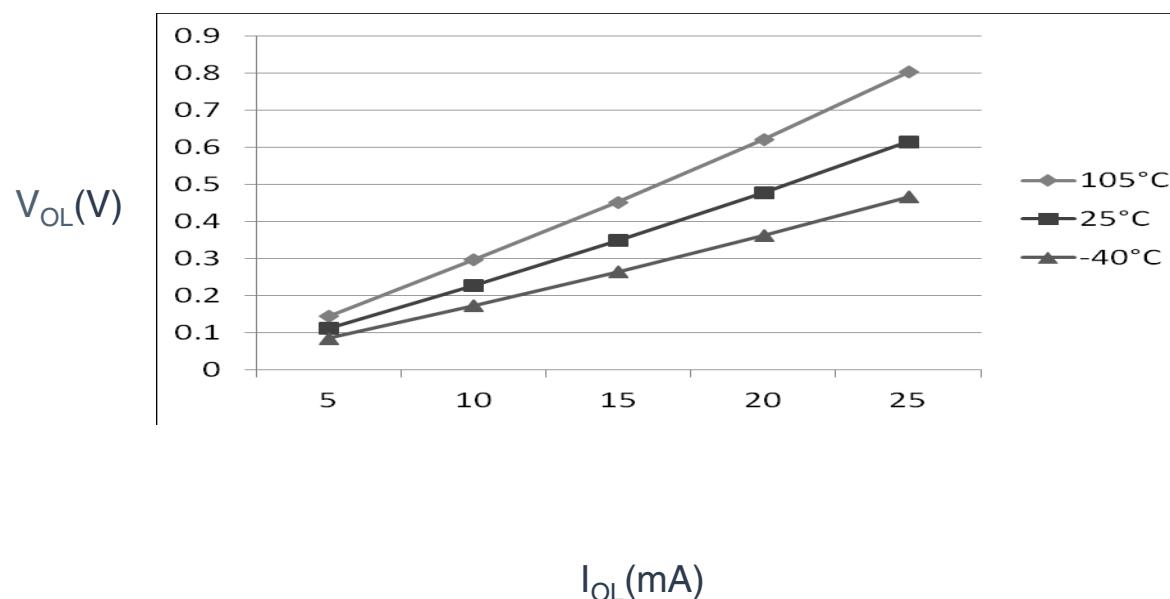


Figure 8. Typical V_{OL} Vs. I_{OL} (high drive strength) ($V_{DD} = 3$ V)

Table 5. Supply current characteristics (continued)

C	Parameter	Symbol	Core/Bus Freq	V _{DD} (V)	Typical ¹	Max ²	Unit	Temp
C	ADC adder to Stop ADLPC = 1 ADLSMP = 1 ADCO = 1	—	—	5	86 (64-, 44-pin packages) 42 (32-pin package)	—	μA	−40 to 105 °C
	MODE = 10B ADICLK = 11B				3	82 (64-, 44-pin packages) 41 (32-pin package)		
C	ACMP adder to Stop	—	—	5	12	—	μA	−40 to 105 °C
				3	12	—		
C	LVD adder to stop ⁴	—	—	5	128	—	μA	−40 to 105 °C
				3	124	—		

1. Data in Typical column was characterized at 5.0 V, 25 °C or is typical recommended value.
2. The Max current is observed at high temperature of 105 °C.
3. RTC adder causes I_{DD} to increase typically by less than 1 μA; RTC clock source is 1 kHz LPO clock.
4. LVD is periodically woken up from Stop by 5% duty cycle. The period is equal to or less than 2 ms.

5.1.3 EMC performance

Electromagnetic compatibility (EMC) performance is highly dependent on the environment in which the MCU resides. Board design and layout, circuit topology choices, location and characteristics of external components as well as MCU software operation play a significant role in EMC performance. The system designer must consult the following applications notes, available on nxp.com for advice and guidance specifically targeted at optimizing EMC performance.

- AN2321: Designing for Board Level Electromagnetic Compatibility
- AN1050: Designing for Electromagnetic Compatibility (EMC) with HCMOS Microcontrollers
- AN1263: Designing for Electromagnetic Compatibility with Single-Chip Microcontrollers
- AN2764: Improving the Transient Immunity Performance of Microcontroller-Based Applications
- AN1259: System Design and Layout Techniques for Noise Reduction in MCU-Based Systems

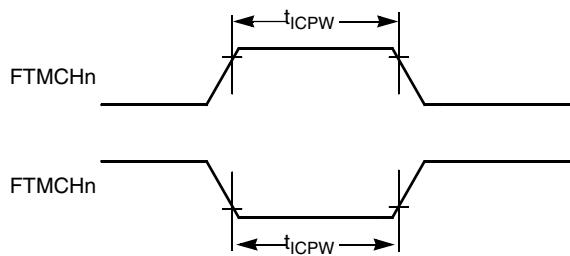


Figure 12. Timer input capture pulse

5.3 Thermal specifications

5.3.1 Thermal operating requirements

Table 9. Thermal operating requirements

Symbol	Description	Min.	Max.	Unit	Notes
T _J	Die junction temperature	-40	125	°C	
T _A	Ambient temperature	-40	105	°C	1

1. Maximum T_A can be exceeded only if the user ensures that T_J does not exceed maximum T_J. The simplest method to determine T_J is: T_J = T_A + θ_{JA} × chip power dissipation

5.3.2 Thermal characteristics

This section provides information about operating temperature range, power dissipation, and package thermal resistance. Power dissipation on I/O pins is usually small compared to the power dissipation in on-chip logic and voltage regulator circuits, and it is user-determined rather than being controlled by the MCU design. To take P_{I/O} into account in power calculations, determine the difference between actual pin voltage and V_{SS} or V_{DD} and multiply by the pin current for each I/O pin. Except in cases of unusually high pin current (heavy loads), the difference between pin voltage and V_{SS} or V_{DD} will be very small.

Table 10. Thermal attributes

Board type	Symbol	Description	64 LQFP	64 QFP	44 LQFP	32 LQFP	Unit	Notes
Single-layer (1S)	R _{θJA}	Thermal resistance, junction to ambient (natural convection)	71	61	75	86	°C/W	1, 2
Four-layer (2s2p)	R _{θJA}	Thermal resistance, junction to ambient (natural convection)	53	47	53	57	°C/W	1, 3

Table continues on the next page...

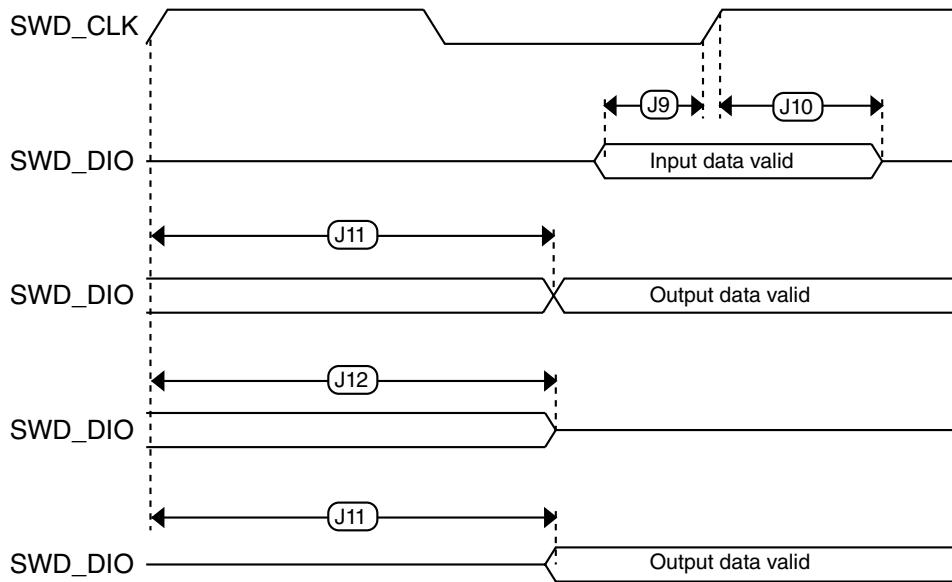


Figure 14. Serial wire data timing

6.2 External oscillator (OSC) and ICS characteristics

Table 12. OSC and ICS specifications (temperature range = -40 to 105 °C ambient)

Num	C	Characteristic		Symbol	Min	Typical ¹	Max	Unit
1	C	Crystal or resonator frequency	Low range (RANGE = 0)	f_{lo}	31.25	32.768	39.0625	kHz
	C		High range (RANGE = 1)	f_{hi}	4	—	20	MHz
2	D	Load capacitors		C1, C2	See Note ²			
3	D	Feedback resistor	Low Frequency, Low-Power Mode ³	R_F	—	—	—	MΩ
			Low Frequency, High-Gain Mode		—	10	—	MΩ
			High Frequency, Low-Power Mode		—	1	—	MΩ
			High Frequency, High-Gain Mode		—	1	—	MΩ
4	D	Series resistor - Low Frequency	Low-Power Mode ³	R_S	—	0	—	kΩ
			High-Gain Mode		—	200	—	kΩ
5	D	Series resistor - High Frequency	Low-Power Mode ³	R_S	—	0	—	kΩ

Table continues on the next page...

**Table 13. Flash and EEPROM characteristics
(continued)**

C	Characteristic	Symbol	Min ¹	Typical ²	Max ³	Unit ⁴
D	Erase Flash Sector	t _{ERSPG}	19.10	20.05	20.08	ms
D	Erase EEPROM Sector	t _{DERSPG}	4.81	5.05	20.57	ms
D	Unsecure Flash	t _{UNSECU}	96.01	100.78	101.48	ms
D	Verify Backdoor Access Key	t _{VFYKEY}	—	—	464	t _{cyc}
D	Set User Margin Level	t _{MLOADU}	—	—	407	t _{cyc}
C	FLASH Program/erase endurance T _L to T _H = -40 °C to 105 °C	n _{FLPE}	10 k	100 k	—	Cycles
C	EEPROM Program/erase endurance T _L to T _H = -40 °C to 105 °C	n _{FLPE}	50 k	500 k	—	Cycles
C	Data retention at an average junction temperature of T _{Javg} = 85°C after up to 10,000 program/erase cycles	t _{D_ret}	15	100	—	years

1. Minimum times are based on maximum f_{NVMOP} and maximum f_{NVMBUS}2. Typical times are based on typical f_{NVMOP} and maximum f_{NVMBUS}3. Maximum times are based on typical f_{NVMOP} and typical f_{NVMBUS} plus aging4. t_{cyc} = 1 / f_{NVMBUS}

Program and erase operations do not require any special power sources other than the normal V_{DD} supply. For more detailed information about program/erase operations, see the Flash Memory Module section in the reference manual.

6.4 Analog

6.4.1 ADC characteristics

Table 14. 5 V 12-bit ADC operating conditions

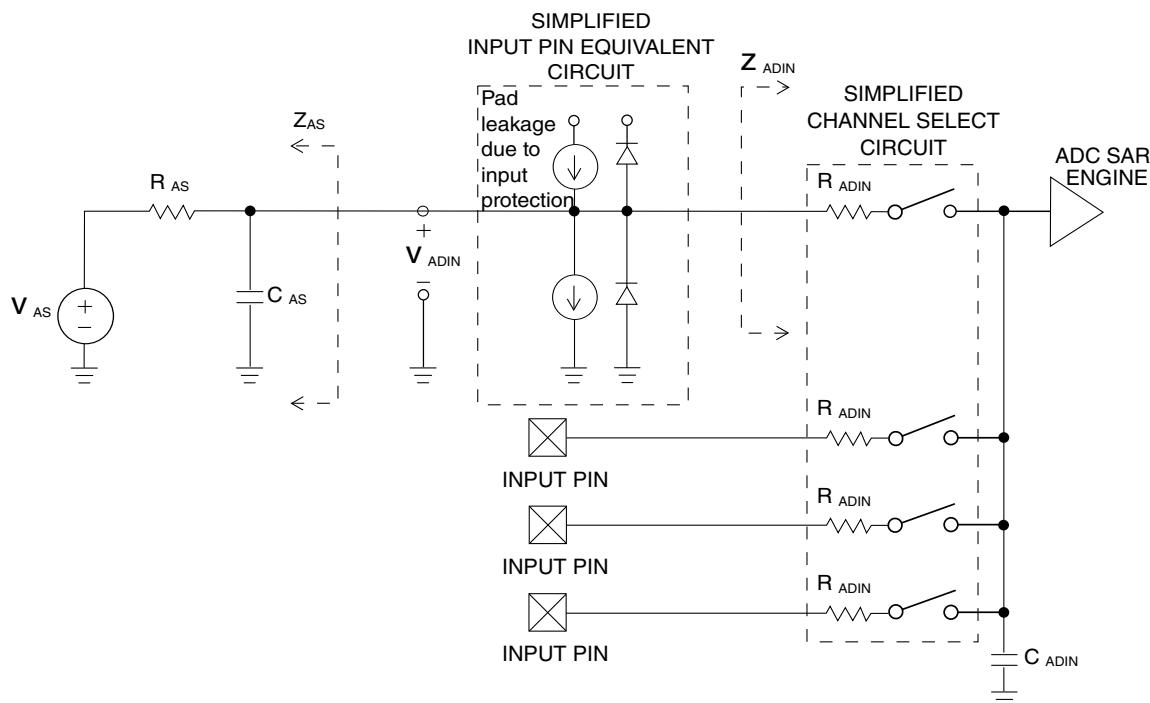
Characteristic	Conditions	Symbol	Min	Typ ¹	Max	Unit	Comment
Reference potential	• Low • High	V _{REFL} V _{REFH}	V _{SSA} V _{DDA}	— —	V _{SSA} V _{DDA}	V	—
Supply voltage	Absolute	V _{DDA}	2.7	—	5.5	V	—
	Delta to V _{DD} (V _{DD} -V _{DDA})	ΔV _{DDA}	-100	0	+100	mV	—
Ground voltage	Delta to V _{SS} (V _{SS} -V _{SSA})	ΔV _{SSA}	-100	0	+100	mV	—
Input voltage		V _{ADIN}	V _{REFL}	—	V _{REFH}	V	—
Input capacitance		C _{ADIN}	—	4.5	5.5	pF	—

Table continues on the next page...

Table 14. 5 V 12-bit ADC operating conditions (continued)

Characteristic	Conditions	Symbol	Min	Typ ¹	Max	Unit	Comment
Input resistance		R_{ADIN}	—	3	5	kΩ	—
Analog source resistance	12-bit mode	R_{AS}	—	—	2	kΩ	External to MCU
	• $f_{ADCK} > 4$ MHz		—	—	5		
	10-bit mode	R_{AS}	—	—	5		
	• $f_{ADCK} > 4$ MHz		—	—	10		
	8-bit mode (all valid f_{ADCK})	R_{AS}	—	—	10		
	High speed (ADLPC=0)		0.4	—	8.0	MHz	—
ADC conversion clock frequency	Low power (ADLPC=1)	f_{ADCK}	0.4	—	4.0		

1. Typical values assume $V_{DDA} = 5.0$ V, Temp = 25°C, $f_{ADCK}=1.0$ MHz unless otherwise stated. Typical values are for reference only and are not tested in production.

**Figure 16. ADC input impedance equivalency diagram****Table 15. 12-bit ADC characteristics ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SSA}$)**

Characteristic	Conditions	C	Symbol	Min	Typ ¹	Max	Unit
Supply current		T	I_{DDA}	—	133	—	μA
ADLPC = 1							
ADLSMP = 1							

Table continues on the next page...

Peripheral operating requirements and behaviors

Table 15. 12-bit ADC characteristics ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SSA}$) (continued)

Characteristic	Conditions	C	Symbol	Min	Typ ¹	Max	Unit
ADCO = 1				—	—	—	
Supply current ADLPC = 1 ADLSMP = 0 ADCO = 1		T	I _{DDA}	—	218	—	µA
Supply current ADLPC = 0 ADLSMP = 1 ADCO = 1		T	I _{DDA}	—	327	—	µA
Supply current ADLPC = 0 ADLSMP = 0 ADCO = 1		T	I _{DDA}	—	582	990	µA
Supply current Stop, reset, module off		T	I _{DDA}	—	0.011	1	µA
ADC asynchronous clock source	High speed (ADLPC = 0)	P	f _{ADACK}	2	3.3	5	MHz
	Low power (ADLPC = 1)			1.25	2	3.3	
Conversion time (including sample time)	Short sample (ADLSMP = 0)	T	t _{ADC}	—	20	—	ADCK cycles
	Long sample (ADLSMP = 1)			—	40	—	
Sample time	Short sample (ADLSMP = 0)	T	t _{ADS}	—	3.5	—	ADCK cycles
	Long sample (ADLSMP = 1)			—	23.5	—	
Total unadjusted Error ²	12-bit mode ³	T	E _{TUE}	—	±3.6	—	LSB ⁴
	10-bit mode	P		—	±1.5	±2.0	
	8-bit mode	T		—	±0.7	±1.0	
Differential Non-Liniarity	12-bit mode	T	DNL	—	±1.0	—	LSB ⁴
	10-bit mode ⁵	P		—	±0.25	±0.5	
	8-bit mode ⁵	T		—	±0.15	±0.25	
Integral Non-Linearity	12-bit mode ³	T	INL	—	±1.0	—	LSB ⁴
	10-bit mode	T		—	±0.3	±0.5	
	8-bit mode	T		—	±0.15	±0.25	
Zero-scale error ⁶	12-bit mode	C	E _{ZS}	—	±2.0	—	LSB ⁴
	10-bit mode	P		—	±0.25	±1.0	
	8-bit mode	T		—	±0.65	±1.0	
Full-scale error ⁷	12-bit mode	T	E _{FS}	—	±2.5	—	LSB ⁴
	10-bit mode	T		—	±0.5	±1.0	

Table continues on the next page...

Table 15. 12-bit ADC characteristics ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SSA}$) (continued)

Characteristic	Conditions	C	Symbol	Min	Typ ¹	Max	Unit
	8-bit mode	T		—	±0.5	±1.0	
Quantization error	≤12 bit modes	D	E _Q	—	—	±0.5	LSB ⁴
Input leakage error ⁸	all modes	D	E _{IL}		I _{in} * R _{AS}		mV
Temp sensor slope	-40 °C–25 °C	D	m	—	3.266	—	mV/°C
	25 °C–125 °C			—	3.638	—	
Temp sensor voltage	25 °C	D	V _{TEMP25}	—	1.396	—	V

1. Typical values assume $V_{DDA} = 5.0$ V, Temp = 25 °C, f_{ADCK}=1.0 MHz unless otherwise stated. Typical values are for reference only and are not tested in production.
2. Includes quantization
3. This parameter is valid for the temperature range of 25 °C to 50 °C.
4. 1 LSB = $(V_{REFH} - V_{REFL})/2^N$
5. Monotonicity and no-missing-codes guaranteed in 10-bit and 8-bit modes
6. $V_{ADIN} = V_{SSA}$
7. $V_{ADIN} = V_{DDA}$
8. I_{in} = leakage current (refer to DC characteristics)

6.4.2 Analog comparator (ACMP) electricals

Table 16. Comparator electrical specifications

C	Characteristic	Symbol	Min	Typical	Max	Unit
D	Supply voltage	V _{DDA}	2.7	—	5.5	V
T	Supply current (Operation mode)	I _{DDA}	—	10	20	µA
D	Analog input voltage	V _{A1N}	V _{SS} - 0.3	—	V _{DDA}	V
P	Analog input offset voltage	V _{AIO}	—	—	40	mV
C	Analog comparator hysteresis (HYST=0)	V _H	—	15	20	mV
C	Analog comparator hysteresis (HYST=1)	V _H	—	20	30	mV
T	Supply current (Off mode)	I _{DDAOFF}	—	60	—	nA
C	Propagation Delay	t _D	—	0.4	1	µs

6.5 Communication interfaces

6.5.1 SPI switching specifications

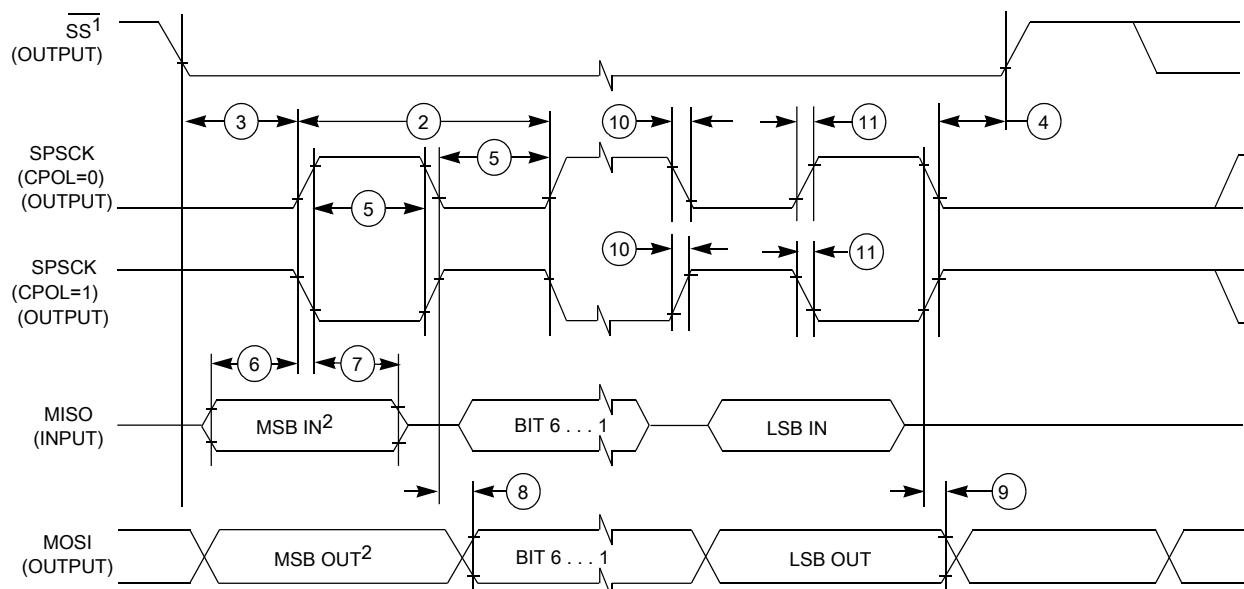
The serial peripheral interface (SPI) provides a synchronous serial bus with master and slave operations. Many of the transfer attributes are programmable. The following tables provide timing characteristics for classic SPI timing modes. See the SPI chapter of the chip's reference manual for information about the modified transfer formats used for

Peripheral operating requirements and behaviors

communicating with slower peripheral devices. All timing is shown with respect to 20% V_{DD} and 80% V_{DD} , unless noted, and 25 pF load on all SPI pins. All timing assumes high-drive strength is enabled for SPI output pins.

Table 17. SPI master mode timing

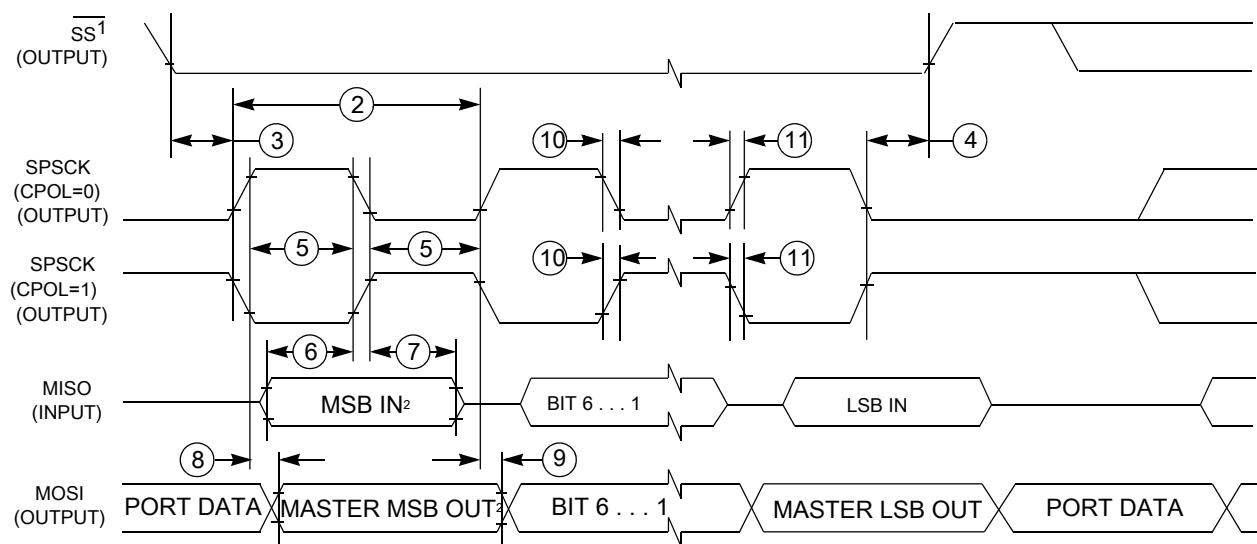
Nu. m.	Symbol	Description	Min.	Max.	Unit	Comment
1	f_{op}	Frequency of operation	$f_{Bus}/2048$	$f_{Bus}/2$	Hz	f_{Bus} is the bus clock
2	t_{SPSCK}	SPSCK period	$2 \times t_{Bus}$	$2048 \times t_{Bus}$	ns	$t_{Bus} = 1/f_{Bus}$
3	t_{Lead}	Enable lead time	1/2	—	t_{SPSCK}	—
4	t_{Lag}	Enable lag time	1/2	—	t_{SPSCK}	—
5	t_{WSPSCK}	Clock (SPSCK) high or low time	$t_{Bus} - 30$	$1024 \times t_{Bus}$	ns	—
6	t_{SU}	Data setup time (inputs)	8	—	ns	—
7	t_{HI}	Data hold time (inputs)	8	—	ns	—
8	t_v	Data valid (after SPSCK edge)	—	25	ns	—
9	t_{HO}	Data hold time (outputs)	20	—	ns	—
10	t_{RI}	Rise time input	—	$t_{Bus} - 25$	ns	—
	t_{FI}	Fall time input	—	—	—	—
11	t_{RO}	Rise time output	—	25	ns	—
	t_{FO}	Fall time output	—	—	—	—



1. If configured as an output.

2. LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

Figure 17. SPI master mode timing (CPHA=0)

**Figure 18. SPI master mode timing (CPHA=1)****Table 18. SPI slave mode timing**

Nu. m.	Symbol	Description	Min.	Max.	Unit	Comment
1	f_{op}	Frequency of operation	0	$f_{Bus}/4$	Hz	f_{Bus} is the bus clock as defined in Control timing .
2	t_{SPSCK}	SPSCK period	$4 \times t_{Bus}$	—	ns	$t_{Bus} = 1/f_{Bus}$
3	t_{Lead}	Enable lead time	1	—	t_{Bus}	—
4	t_{Lag}	Enable lag time	1	—	t_{Bus}	—
5	t_{WSPSCK}	Clock (SPSCK) high or low time	$t_{Bus} - 30$	—	ns	—
6	t_{SU}	Data setup time (inputs)	15	—	ns	—
7	t_{HI}	Data hold time (inputs)	25	—	ns	—
8	t_a	Slave access time	—	t_{Bus}	ns	Time to data active from high-impedance state
9	t_{dis}	Slave MISO disable time	—	t_{Bus}	ns	Hold time to high-impedance state
10	t_v	Data valid (after SPSCK edge)	—	25	ns	—
11	t_{HO}	Data hold time (outputs)	0	—	ns	—
12	t_{RI}	Rise time input	—	$t_{Bus} - 25$	ns	—
	t_{FI}	Fall time input	—			
13	t_{RO}	Rise time output	—	25	ns	—
	t_{FO}	Fall time output	—			

Dimensions

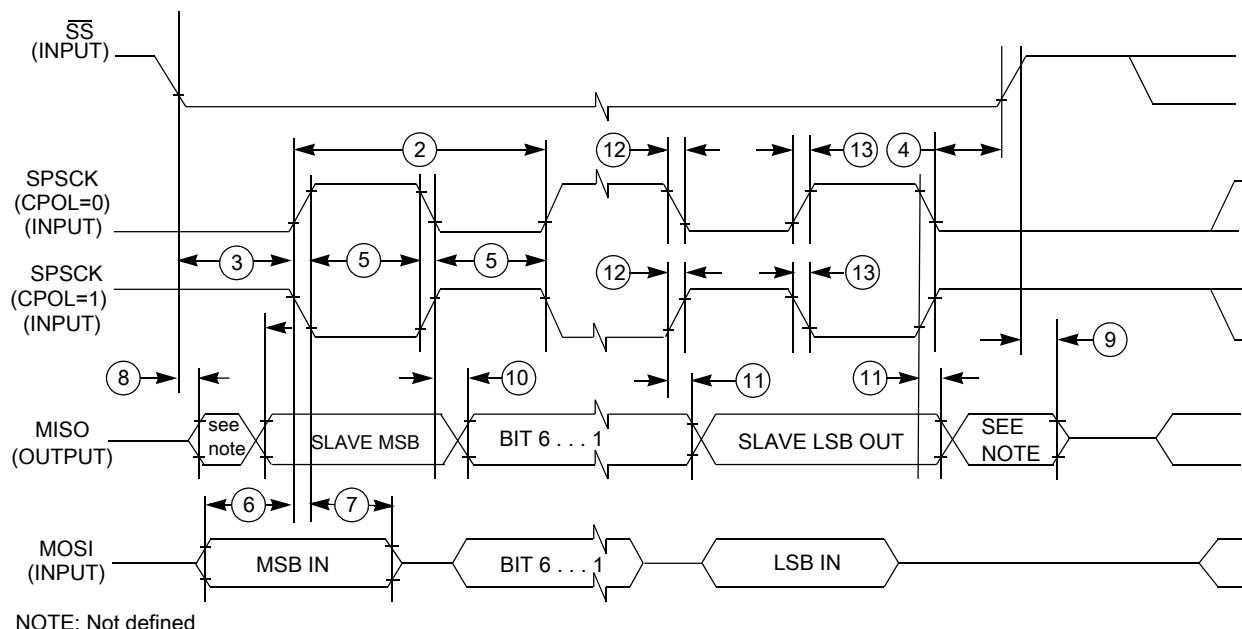


Figure 19. SPI slave mode timing (CPHA = 0)

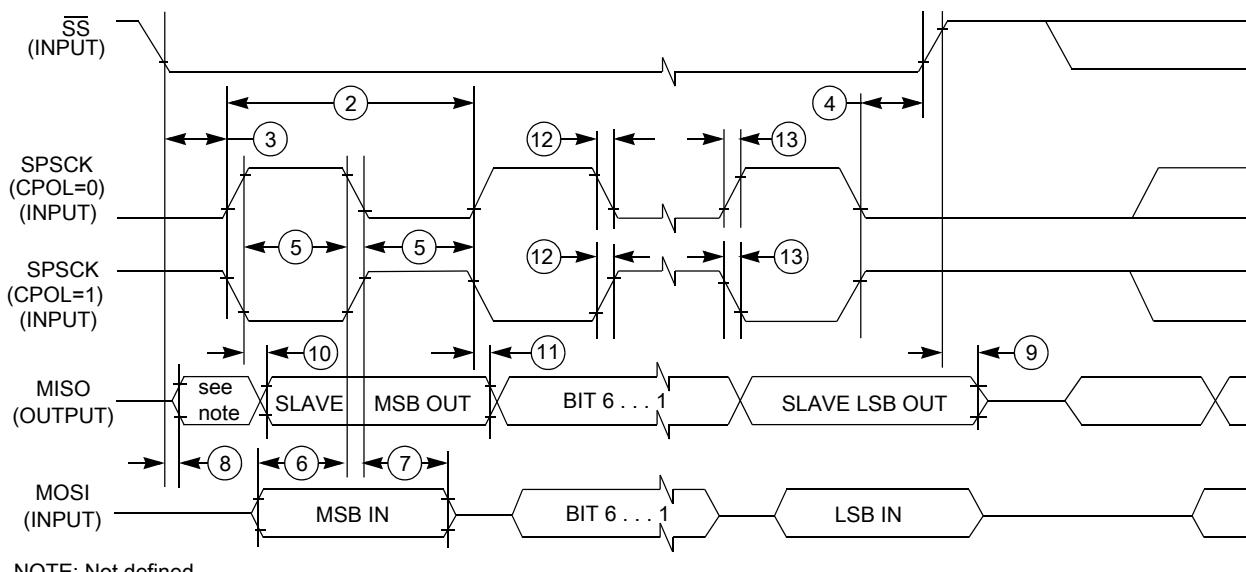


Figure 20. SPI slave mode timing (CPHA=1)

7 Dimensions

7.1 Obtaining package dimensions

Package dimensions are provided in package drawings.

To find a package drawing, go to nxp.com and perform a keyword search for the drawing's document number:

If you want the drawing for this package	Then use this document number
32-pin LQFP	98ASH70029A
44-pin LQFP	98ASS23225W
64-pin QFP	98ASB42844B
64-pin LQFP	98ASS23234W

8 Pinout

8.1 Signal multiplexing and pin assignments

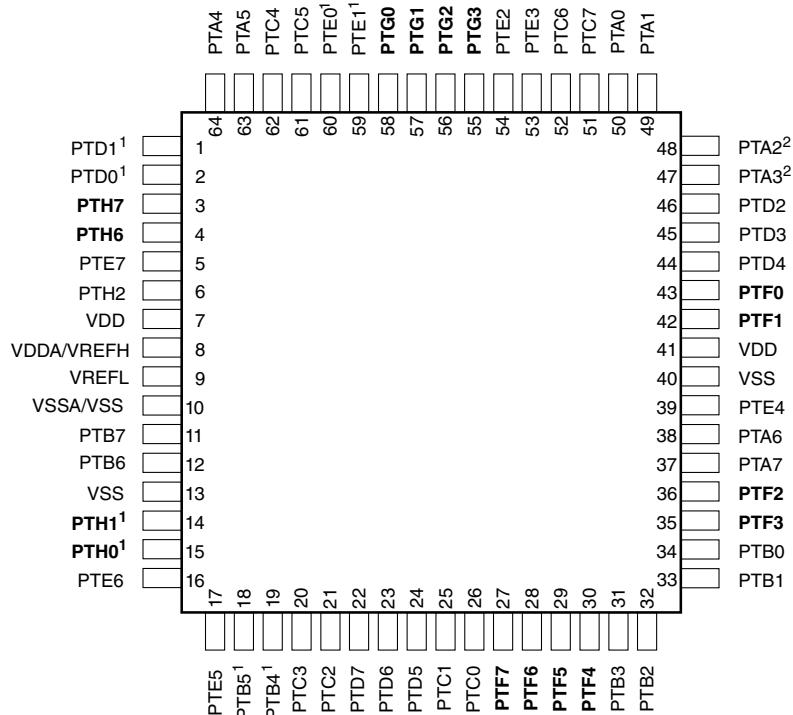
The following table shows the signals available on each pin and the locations of these pins on the devices supported by this document. The Port Control Module is responsible for selecting which ALT functionality is available on each pin.

Table 19. Pin availability by package pin-count

Pin Number			Lowest Priority <-- --> Highest				
64-QFP/ LQFP	44-LQFP	32-LQFP	Port Pin	Alt 1	Alt 2	Alt 3	Alt 4
1	1	1	PTD1 ¹	KBI1_P1	FTM2_CH3	SPI1_MOSI	—
2	2	2	PTD0 ¹	KBI1_P0	FTM2_CH2	SPI1_SCK	—
3	—	—	PTH7	—	—	—	—
4	—	—	PTH6	—	—	—	—
5	3	—	PTE7	—	FTM2_CLK	—	FTM1_CH1
6	4	—	PTH2	—	BUSOUT	—	FTM1_CH0
7	5	3	—	—	—	—	VDD
8	6	4	—	—	—	VDDA	VREFH ²
9	7	5	—	—	—	—	VREFL
10	8	6	—	—	—	VSSA	VSS ³
11	9	7	PTB7	—	I2C0_SCL	—	EXTAL
12	10	8	PTB6	—	I2C0_SDA	—	XTAL
13	11	—	—	—	—	—	VSS
14	—	—	PTH1 ¹	—	FTM2_CH1	—	—
15	—	—	PTH0 ¹	—	FTM2_CH0	—	—
16	—	—	PTE6	—	—	—	—
17	—	—	PTE5	—	—	—	—
18	12	9	PTB5 ¹	FTM2_CH5	SPI0_PCS0	ACMP1_OUT	—

Table continues on the next page...

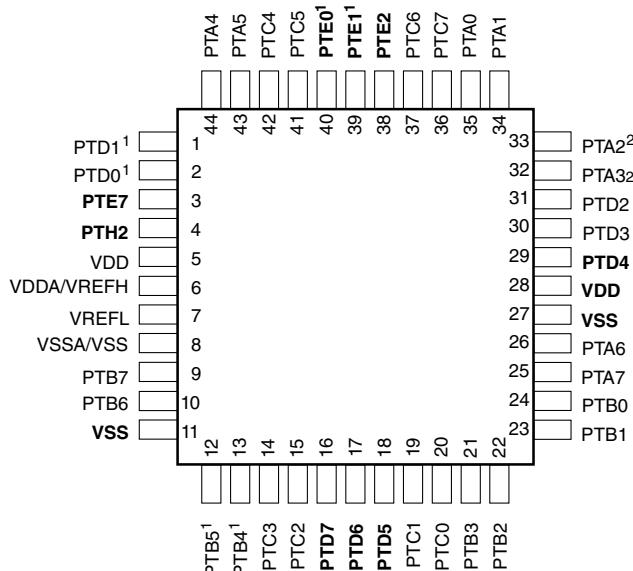
Pinout



Pins in **bold** are not available on less pin-count packages.

1. High source/sink current pins
2. True open drain pins

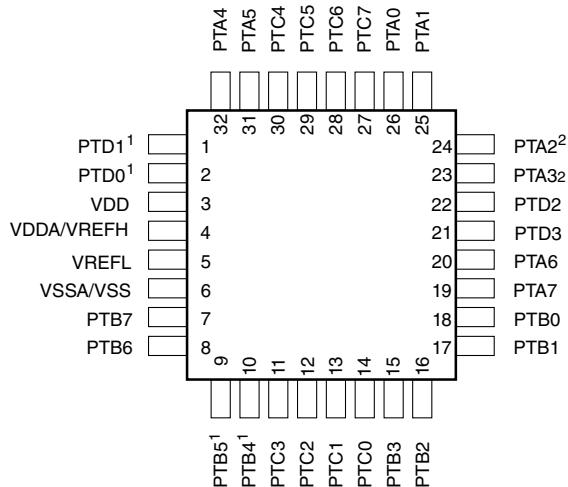
Figure 21. 64-pin QFP/LQFP packages



Pins in **bold** are not available on less pin-count packages.

1. High source/sink current pins
2. True open drain pins

Figure 22. 44-pin LQFP package

**Figure 23. 32-pin LQFP package**

9 Revision history

The following table provides a revision history for this document.

Table 20. Revision history

Rev. No.	Date	Substantial Changes
3	07/2013	Initial public release.
4	10/2014	<ul style="list-style-type: none"> Updated all the V_{DDAD} to V_{DDA}, V_{SSAD} to V_{SSA} Updated the features of OSC, ICS, UART, KBI and ADC in the front page Updated I_{LAT} and V_{CDM} in the ESD handling ratings Added V_{IN} and removed V_{DIO}, V_{AIO} in the Voltage and current operating ratings Updated DC characteristics Added the item of ACMP adder to Stop and a note to the Max. in Supply current characteristics Added EMC radiated emissions operating behaviors Added f_{Sys} and a note to t_{IHIL} in the Control timing Added a new section of Thermal operating requirements Updated J1, J10 and J11 in the SWD electricals Updated External oscillator (OSC) and ICS characteristics Added reference potential and a note to the E_{TUE} and E_{ZS} in ADC characteristics Updated SPI switching specifications
5	07/2016	<ul style="list-style-type: none"> Updated the Typical value of E_{TUE} in 12-bit mode and added a note to the 12-bit mode of E_{TUE} and INL in the ADC characteristics.

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